

10124 Translator

Quad TTL-to-ECL Translator
Product Specification

ECL Products

DESCRIPTION

The 10124 is a Quad TTL-ECL Translator with an individual Data and a common Select TTL-compatible input on each gate. When the Select input is in the LOW state, all ECL non-inverting outputs are in a LOW state and inverting outputs are in a HIGH state.

TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (-I _{EE})
10124	3.5ns	53mA

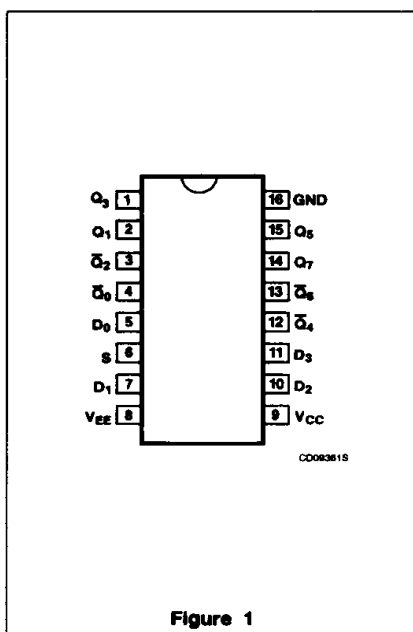
ORDERING CODE

PACKAGES	COMMERCIAL RANGE V _{CC} = +5V, GND = 0V, V _{EE} = -5.2V T _A = -30°C to +85°C
Plastic DIP	10124N
Ceramic DIP	10124F

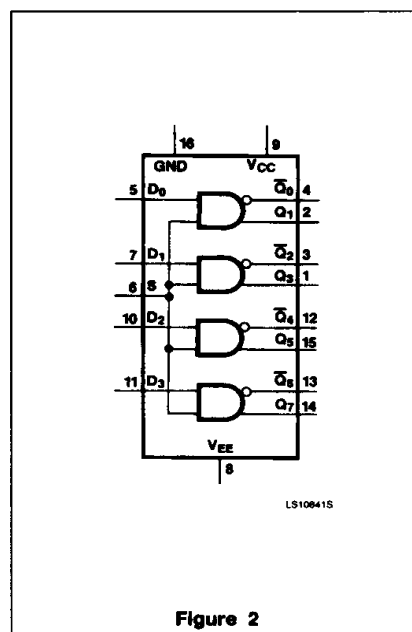
PIN DESCRIPTION

PINS	DESCRIPTION
D ₀ - D ₃	Data Inputs (Schottky TTL)
S	Select Input (Schottky TTL)
Q ₁ , Q ₃ , Q ₅ , Q ₇	Data Outputs (AND) (10K ECL)
\bar{Q}_0 , \bar{Q}_2 , \bar{Q}_4 , \bar{Q}_6	Data Outputs (NAND) (10K ECL)

PIN CONFIGURATION



LOGIC SYMBOL



January 30, 1986

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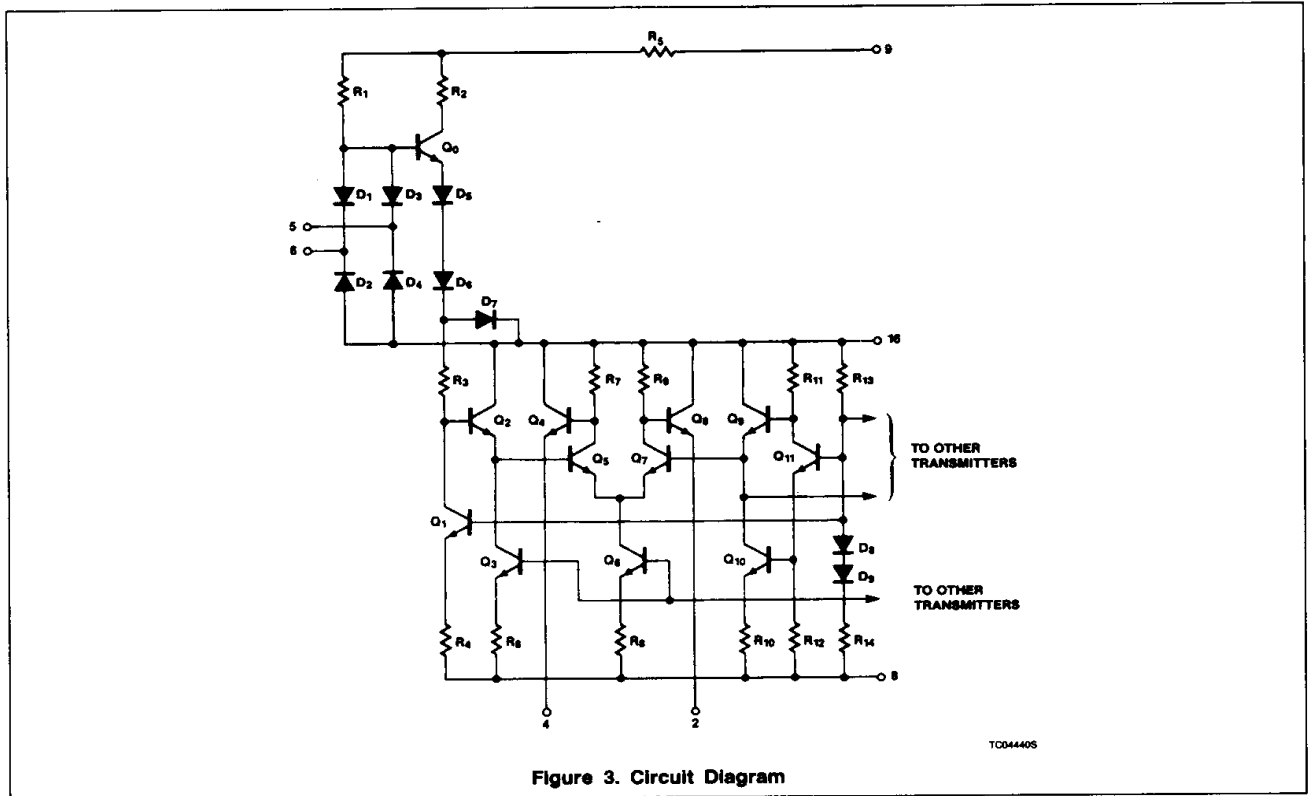


Figure 3. Circuit Diagram

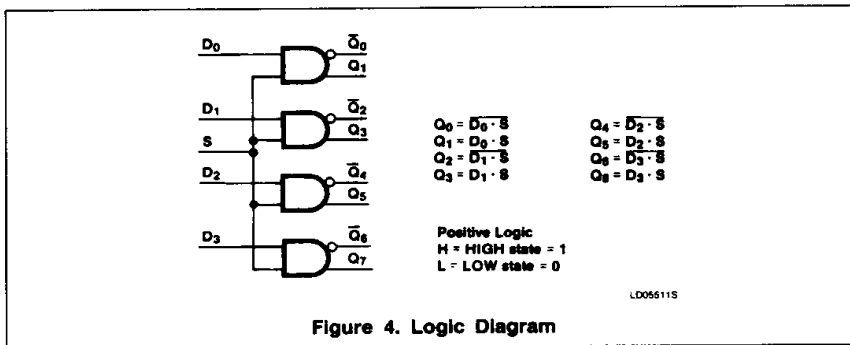


Figure 4. Logic Diagram

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ABSOLUTE MAXIMUM RATINGS (Operation beyond the limits set forth in this table may impair useful life of the device. Unless otherwise noted, these limits are specified over the operating ambient temperature range.)

PARAMETER		10K ECL	UNIT
V _{EE}	Supply voltage (negative)	-8.0	V
V _{CC}	Supply voltage (positive)	+7.0	V
V _{IN}	Input voltage (V _{IN} should never be more positive than V _{CC3})	0 to V _{CC}	V
I _O	Output current	-50	mA
T _S	Storage temperature	-55 to +150	°C
T _J	Maximum junction temperature	Ceramic package	+165 °C
		Plastic package	+150 °C

DC OPERATING CONDITIONS

PARAMETER		10K ECL			UNIT
		Min	Nom	Max	
GND	Device ground (common)	0	0	0	V
V _{CC}	Supply voltage (positive)		5.0		V
V _{EE}	Supply voltage (negative)		-5.2		V
V _{IH}	HIGH level input voltage	T _A = -30°C	2.0	4.0	V
		T _A = +25°C	1.8	4.0	V
		T _A = +85°C	1.8	4.0	V
V _{IHT}	HIGH level input threshold voltage	T _A = -30°C	2.0		V
		T _A = +25°C	1.8		V
		T _A = +85°C	1.8		V
V _{ILT}	LOW level input threshold voltage	T _A = -30°C		1.1	V
		T _A = +25°C		1.1	V
		T _A = +85°C		0.9	V
V _{IL}	LOW level input voltage	T _A = -30°C	0.4	1.1	V
		T _A = +25°C	0.4	1.1	V
		T _A = +85°C	0.4	0.8	V
T _A	Operating ambient temperature	-30	+25	+85	°C

NOTE:

When operating at V_{EE} other than specified voltage (-5.2V), the DC and AC Characteristics will vary slightly from specified values. (See table of DC Characteristics)

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DC ELECTRICAL CHARACTERISTICS $GND = 0V$, $V_{CC} = +5.0V \pm 0.010V$, $V_{EE} = -5.2V \pm 0.010V$, $T_A = -30^\circ C$ to $+85^\circ C$, output loading with 50Ω to $-2.0V \pm 0.010V$ unless otherwise specified^{1,3}

PARAMETER		MIN	TYP	MAX	UNIT	TEST CONDITIONS ²	
V _{OH}	HIGH level output voltage	T _A = -30°C	-1060		-890	mV	For Q _n outputs, apply V _{IHmax} to all inputs. For \bar{Q}_n outputs, apply V _{ILmin} to all inputs.
		T _A = +25°C	-960		-810	mV	
		T _A = +85°C	-890		-700	mV	
V _{OHT}	HIGH level output threshold voltage	T _A = -30°C	-1080			mV	For Q _n outputs, apply V _{IHT} to D ₁ input with V _{IHmax} applied to all other inputs. For \bar{Q}_n outputs, apply V _{ILT} to D ₁ input with V _{IHmax} applied to all other inputs.
		T _A = +25°C	-980			mV	
		T _A = +85°C	-910			mV	
V _{OLT}	LOW level output threshold voltage	T _A = -30°C			-1655	mV	For Q _n outputs, apply V _{ILT} to D ₁ input with V _{IHmax} applied to all other inputs. For \bar{Q}_n outputs, apply V _{IHT} to D ₁ input with V _{IHmax} applied to all other inputs.
		T _A = +25°C			-1630	mV	
		T _A = +85°C			-1595	mV	
V _{OL}	LOW level output voltage	T _A = -30°C	-1890		-1675	mV	For Q _n outputs, apply V _{ILmin} to all inputs. For \bar{Q}_n outputs, apply V _{IHmax} to all inputs.
		T _A = +25°C	-1850		-1650	mV	
		T _A = +85°C	-1825		-1615	mV	
-I _{EE}	V _{EE} supply current	T _A = -30°C			72	mA	Apply V _{IHmax} to all inputs.
		T _A = +25°C		53	66	mA	
		T _A = +85°C			72	mA	
$\frac{\Delta V_{OH}}{\Delta V_{EE}}$	HIGH level output voltage compensation			0.016		V/V	T _A = +25°C
$\frac{\Delta V_{OL}}{\Delta V_{EE}}$	LOW level output voltage compensation			0.250		V/V	
$\frac{\Delta V_{BB}}{\Delta V_{EE}}$	Reference Bias voltage compensation			0.148		V/V	

NOTES:

- The specified limits represent the "worst case" value for the parameter. Since these "worst case" values normally occur at the temperature extremes, additional noise immunity and guard banding can be achieved by decreasing the allowable system operating ranges.
- Conditions for testing shown in the tables are not necessarily worst case. For worst-case testing guidelines, refer to Section 3 Testing, DC testing.
- The specified limits shown in the DC Characteristics can be met only after thermal equilibrium has been established. Thermal equilibrium is established by applying power for at least 2 minutes while maintaining transverse air flow of 2.5 meters/s (500 linear feet/min) over the device either mounted in the test socket or on the printed circuit board. Test voltage values are given in the DC Operating Conditions and defined in Figure 5.

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DC ELECTRICAL CHARACTERISTICS GND = 0V, $V_{CC} = +5.0V \pm 0.010V$, $V_{EE} = -5.2V \pm 0.010V$, $T_A = -30^\circ C$ to $+85^\circ C$. Output loading with 50Ω to $-2.0V \pm 0.010V$ unless otherwise specified

PARAMETER		MIN	TYP	MAX	UNIT	TEST CONDITIONS
V_{IK}	Clamp input voltage			-1.5	V	Apply -20mA to S input.
						Apply -10mA to each input under test, one at a time.
V_{BIN}	Input breakdown voltage	5.5			V	Apply 1.0mA to each input under test, one at a time.
I_F	Forward current			-12.8	mA	Apply VF(0.40V) to S input and VR(2.4V) to all other inputs.
				-3.2	mA	Apply VF(0.40V) to each input under test, one at a time, with VR(2.4V) applied to all other inputs.
I_R	Reverse current			200	μA	Apply VR(2.4V) to S input with VF(0.4V) to all other inputs.
				50	μA	Apply VR(2.4V) to each input under test, one at a time with VF(0.4V) to all other inputs.
I_{CCH}	Supply current HIGH (positive)	$T_A = -30^\circ C$		16	mA	Apply V_{IHmax} to all inputs.
		$T_A = +25^\circ C$		16	mA	
		$T_A = +85^\circ C$		18	mA	
I_{CCL}	Supply current LOW (positive)			25	mA	Ground all inputs.

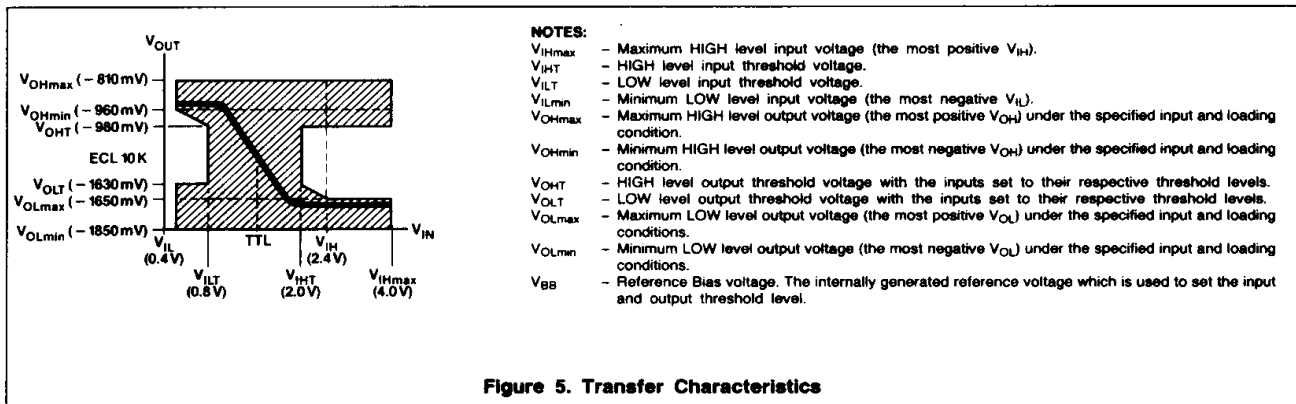


Figure 5. Transfer Characteristics

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AC ELECTRICAL CHARACTERISTICS GND = +2.0V ± 0.010V, V_{CC} = +7.0V ± 0.010V, V_{EE} = -3.2V ± 0.010V, V_T = System Gnd.

PARAMETER	T _A = -30°C		T _A = +25°C			T _A = +85°C		UNIT	TEST CONDITIONS
	Min	Max	Min	Typ	Max	Min	Max		
t _{PLH} Propagation delay	1.0	6.5	1.0	3.5	6.0	1.0	6.5	ns	Figs. 6, 7, 8
t _{PHL} D _n to Q _n , Q̄ _n	1.0	6.5	1.0	3.5	6.0	1.0	6.5	ns	
t _{TLH} Transition time	1.3	4.1	1.3	2.5	3.9	1.3	4.1	ns	Figs. 6, 7, 8
t _{THL} 20% to 80%, 80% to 20%	1.3	4.1	1.3	2.5	3.9	1.3	4.1	ns	

AC WAVEFORMS

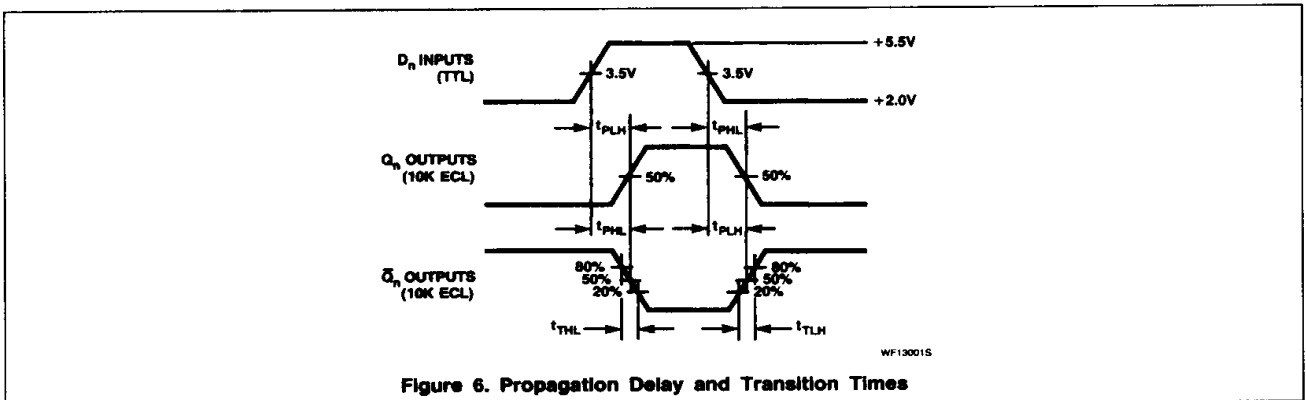


Figure 6. Propagation Delay and Transition Times

TEST CIRCUITS AND WAVEFORMS

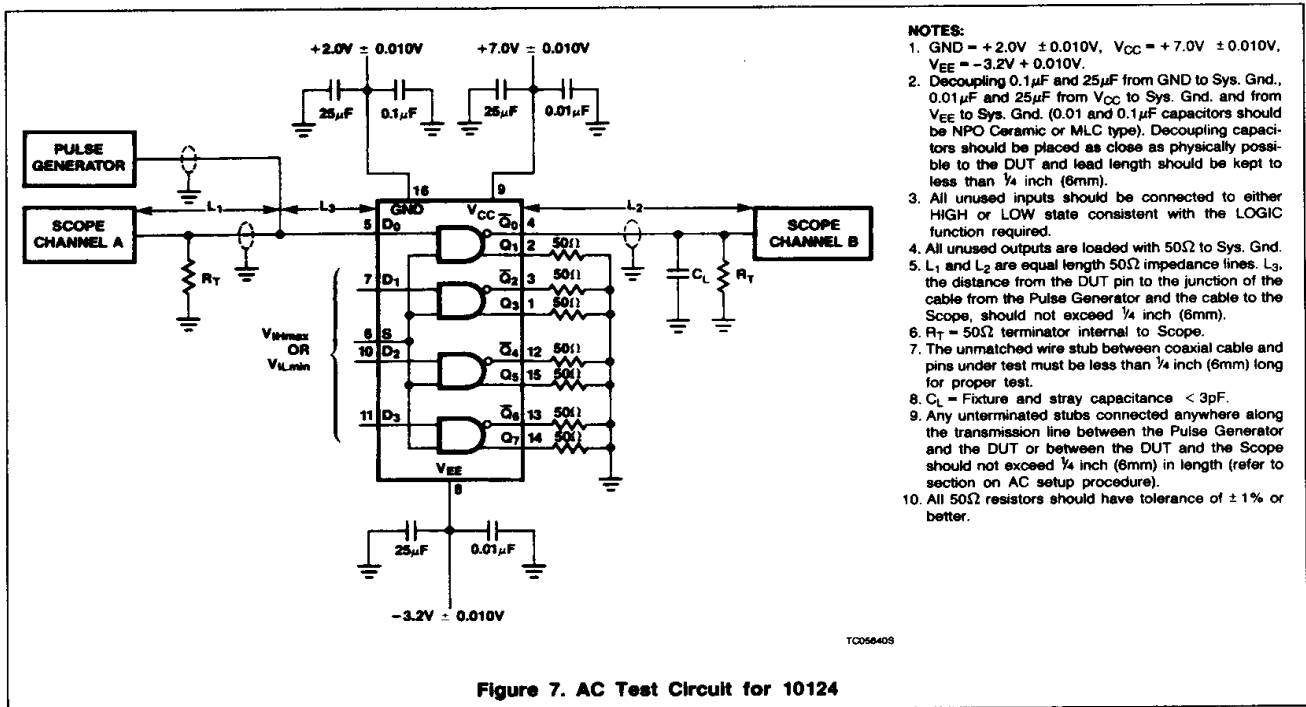


Figure 7. AC Test Circuit for 10124

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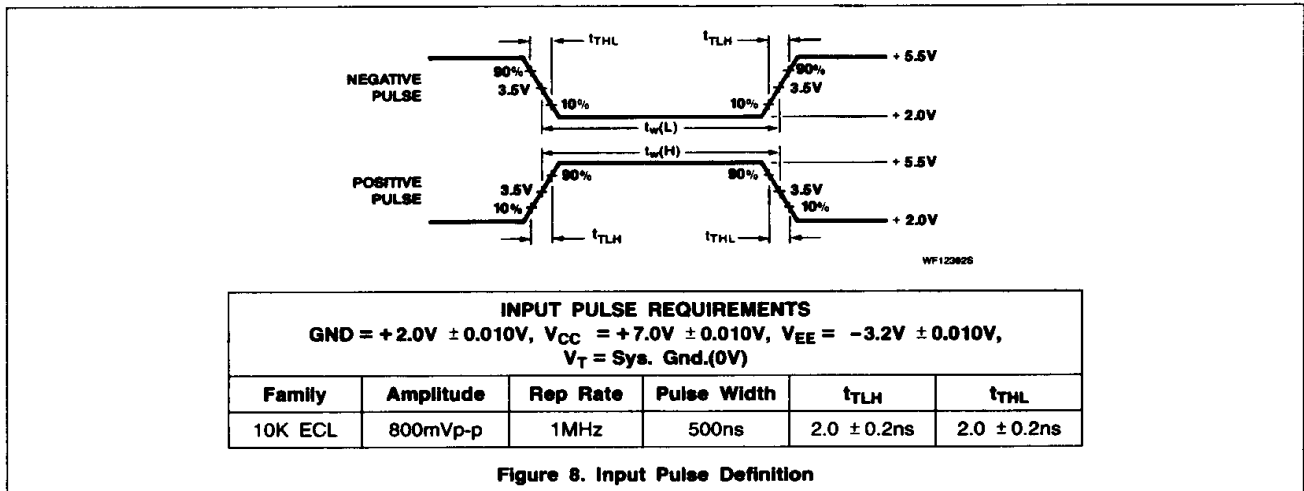


Figure 8. Input Pulse Definition

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